

Features

- Trench Power LV MOSFET Technology
- Excellent Package for Heat Dissipation
- High Density Cell Design for Low $R_{DS(on)}$
- Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

N-CHANNEL MOSFET

Maximum Ratings

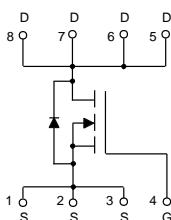
- Operating Junction Temperature Range : -55°C to +175°C
- Storage Temperature Range: -55°C to +175°C
- Thermal Resistance: 5°C/W Junction to Case^(Note 2)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current $T_C=25^\circ\text{C}$	I_D	50	A
		35	A
Pulsed Drain Current ^(Note 3)	I_{DM}	190	A
Single Pulse Avalanche Energy ^(Note 4)	E_{AS}	225	mJ
Total Power Dissipation $T_C=25^\circ\text{C}$	P_D	30	W
		15	W

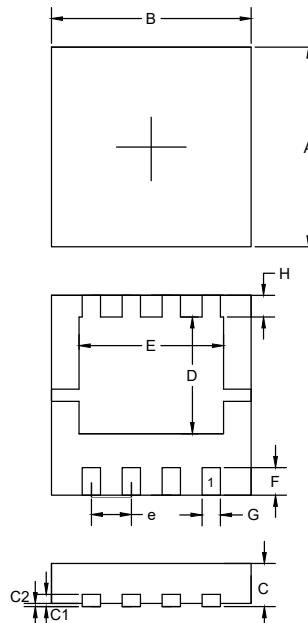
Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. $R_{\theta JA}$ is the Sum of the Junction-to-Case and Case-to-Ambient Thermal Resistance, Where the Case Thermal Reference is Defined as The Solder Mounting Surface of the Drain Pins. $R_{\theta JC}$ is Guaranteed by Design, While $R_{\theta JA}$ is Determined by the Board Design. The Maximum Rating Presented Here is Based on Mounting on a 1 in² pad of 2oz Copper.
3. Pulse Test; Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.
4. $T_J=25^\circ\text{C}$, $V_{DS}=30\text{V}$, $V_{DD}=25\text{V}$, $V_{GS}=10\text{V}$, $L=1\text{mH}$.

Internal Structure



DFN3333



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.126	0.130	3.20	3.30	
B	0.126	0.130	3.20	3.30	
C	0.030	0.033	0.75	0.85	
C1	0.007	0.009	0.18	0.22	
C2	---	0.002	---	0.05	
D	0.071	0.079	1.80	2.00	
E	0.087	0.098	2.20	2.50	
F	0.016	0.020	0.40	0.50	
G	0.010	0.014	0.25	0.35	
H	0.012	0.016	0.30	0.40	
e	0.024	0.028	0.60	0.70	

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	30			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V, V_{GS}=0V$			1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1	1.5	2.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=15A$		4.9	6	$m\Omega$
		$V_{GS}=4.5V, I_D=15A$		6.3	8	
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=20A$			1.2	V
Continuous Body Diode Current	I_S				50	A
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=15V, V_{GS}=0V, f=1MHz$		2150		pF
Output Capacitance	C_{oss}			435		
Reverse Transfer Capacitance	C_{rss}			252		
Total Gate Charge	Q_g	$V_{DS}=15V, V_{GS}=10V, I_D=20A$		52.8		nC
Gate-Source Charge	Q_{gs}			12.3		
Gate-Drain Charge	Q_{gd}			10.8		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V, V_{DD}=20V, I_D=4A, R_L=1\Omega$ $R_{GEN}=3\Omega$		9		ns
Turn-On Rise Time	t_r			15.5		
Turn-Off Delay Time	$t_{d(off)}$			29		
Turn-Off Fall Time	t_f			9		
Gate-Source Leakage Current	I_{GSS}	$I_F=25A, di/dt=100A/\mu s$		28		nC
Zero Gate Voltage Drain Current	I_{DSS}			27		ns

Curve Characteristics

Fig. 1 - Output Characteristics

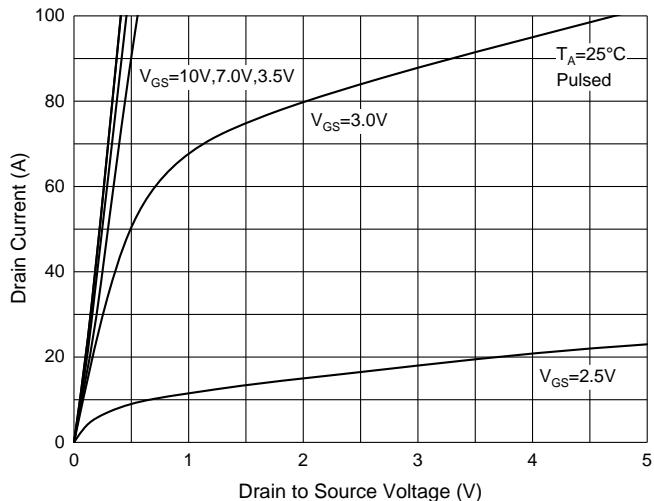


Fig. 2 - Transfer Characteristics

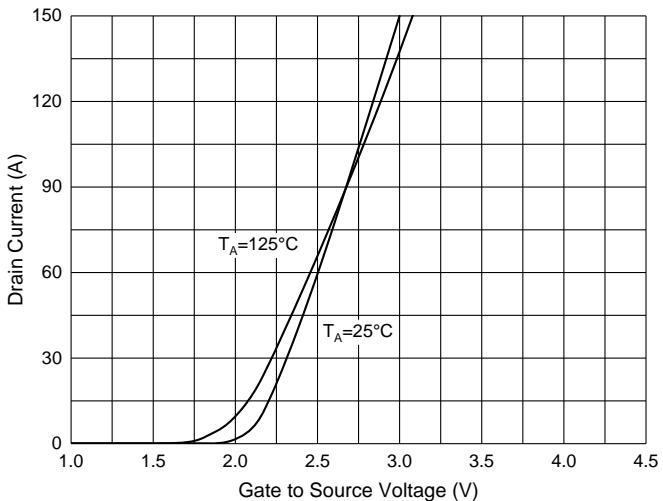


Fig. 3 - Capacitance Characteristics

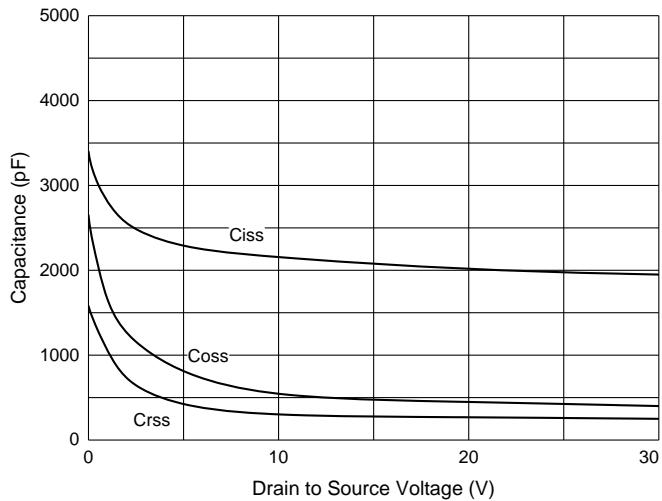


Fig. 4 - Gate Charge

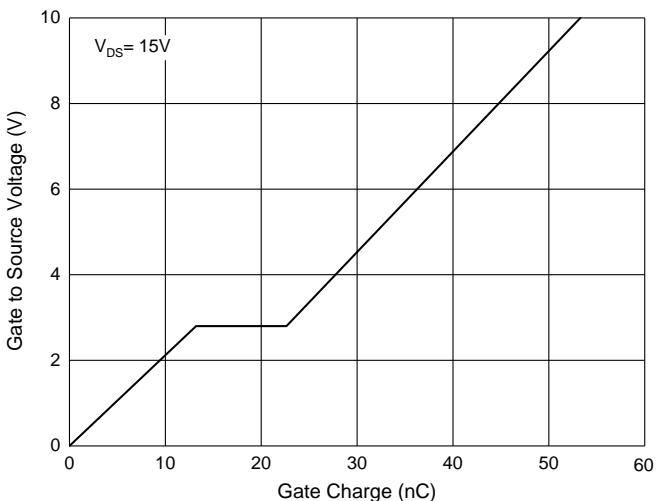


Fig. 5 - $R_{DS(ON)}$ — I_D

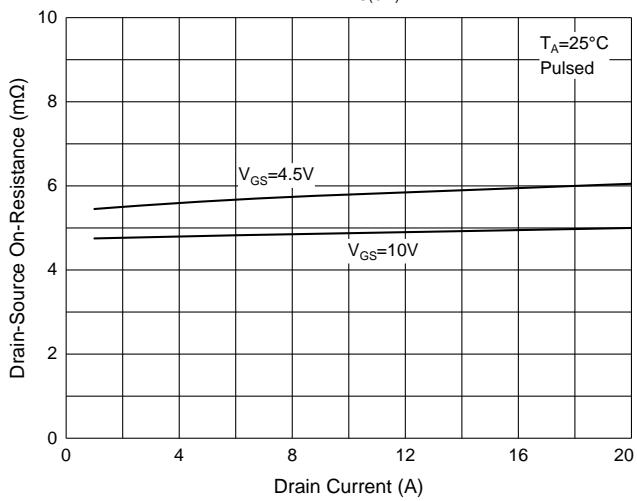
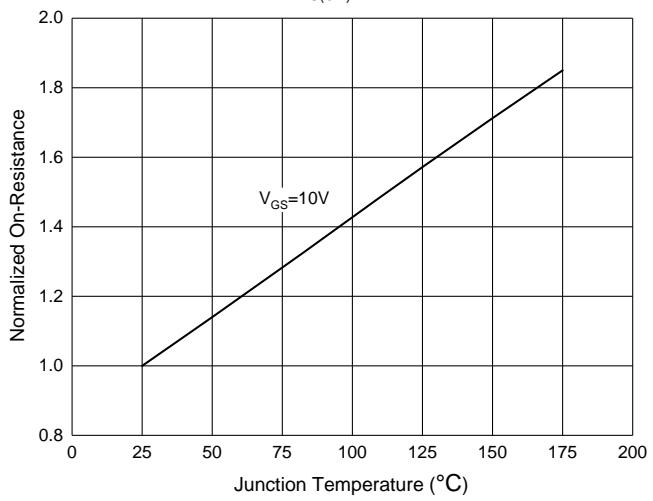


Fig. 6 - $R_{DS(ON)}$ —Temperature



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 5Kpcs/Reel

IMPORTANT NOTICE

Micro Commercial Components Corp. reserves the right to make changes without further notice to any product herein to make corrections, modifications , enhancements , improvements , or other changes . **Micro Commercial Components Corp.** does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights ,nor the rights of others . The user of products in such applications shall assume all risks of such use and will agree to hold **Micro Commercial Components Corp.** and all the companies whose products are represented on our website, harmless against all damages. **Micro Commercial Components Corp.** products are sold subject to the general terms and conditions of commercial sale, as published at <https://www.mccsemi.com/Home/TermsAndConditions>.

LIFE SUPPORT

MCC's products are not authorized for use as critical components in life support devices or systems without the express written approval of Micro Commercial Components Corporation.

CUSTOMER AWARENESS

Counterfeiting of semiconductor parts is a growing problem in the industry. Micro Commercial Components (MCC) is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. MCC strongly encourages customers to purchase MCC parts either directly from MCC or from Authorized MCC Distributors who are listed by country on our web page cited below. Products customers buy either from MCC directly or from Authorized MCC Distributors are genuine parts, have full traceability, meet MCC's quality standards for handling and storage. **MCC will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources.** MCC is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.